

IB05S THRU IB10S

SINGLE PHASE 0.6 AMP SURFACE MOUNT BRIDGE RECTIFIERS

FEATURES:

Glass Passivated Chip Junction
Reverse Voltage - 100 to 1000 V
Average Rectified Output Current- 0.6 A
High Surge Current Capability
Designed for Surface Mount Application

MECHANICAL DATA

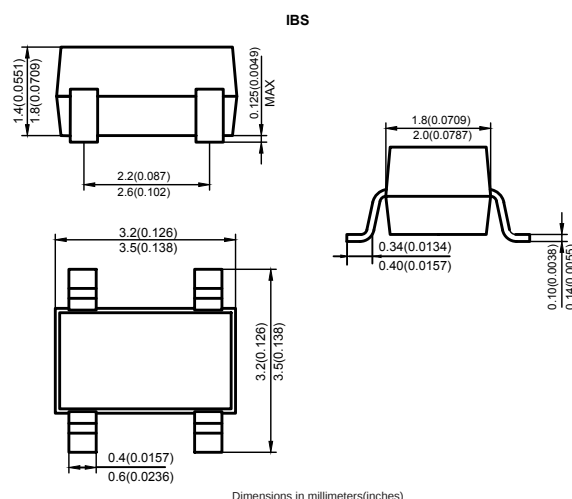
- Case: I B S
- Terminals: Solderable per MIL-STD-750, Method 2026

VOLTAGE RANGE

50 to 1000 Volts

CURRENT

0.6 Ampere



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.
Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

TYPE NUMBER	IB05S	IB1S	IB2S	IB4S	IB6S	IB8S	IB10S	UNIT
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at Ta=40°C(Note 1)	0.6							A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	25							A
I ² t Rating for Fusing (1ms < t < 8.3ms)	2.59							A ² S
Maximum Forward Voltage Drop per Bridge Element at 0.3A D.C.	1.0							V
Maximum DC Reverse Current at Rated DC Blocking Voltage Ta=25°C	5.0							μA
Typical Thermal Resistance R _{JA} (Note 2)	60							°C/W
Operating Temperature Range, T _J	-55 — +150							°C
Storage Temperature Range, T _{STG}	-55 — +150							°C

NOTES: 1. Mounted on P.C. Board.
2. Thermal Resistance Junction to Ambient.

RATING AND CHARACTERISTIC CURVES (IB05S THRU IB10S)

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

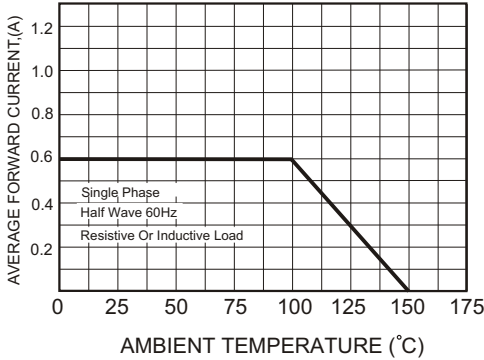


FIG.2-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

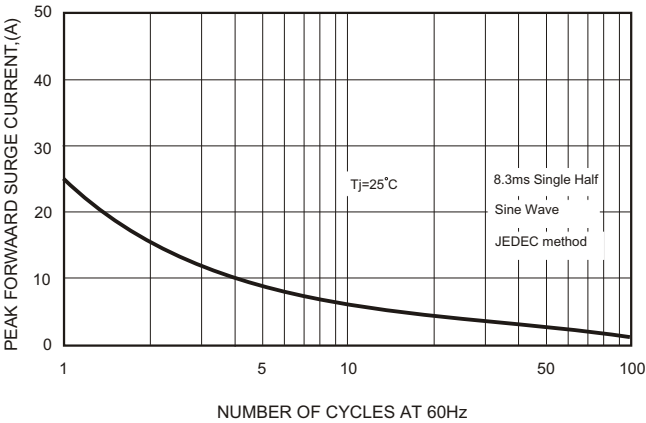


FIG.3-TYPICAL FORWARD CHARACTERISTICS

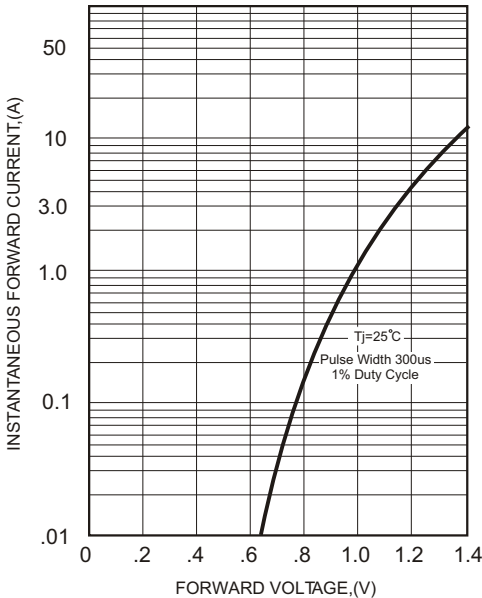


FIG.4-TYPICAL REVERSE CHARACTERISTICS

